

74HC258

Quad 2-input multiplexer; 3-state; inverting

Rev. 04 — 14 April 2008

Product data sheet

1. General description

The 74HC258 is a high-speed Si-gate CMOS device and is pin compatible with low power Schottky TTL (LSTTL). The 74HC258 is specified in compliance with JEDEC standard no. 7A.

The 74HC258 has four identical 2-input multiplexers with 3-state outputs, which select 4 bits of data from two sources and is controlled by a common data select input (S).

The data inputs from source 0 (1I0 to 4I0) are selected when input S is LOW and the data inputs from source 1 (1I1 to 4I1) are selected when S is HIGH.

Data appears at the outputs (1 \bar{Y} to 4 \bar{Y}) in inverted form from the select inputs.

The 74HC258 is the logic implementation of a 4-pole, 2-position switch, where the position of the switch is determined by the logic levels applied to S. The outputs are forced to a high-impedance OFF-state when \overline{OE} is HIGH.

The logic equations for the outputs are:

$$1\bar{Y} = \overline{\overline{OE} \times (1I1 \times S + 1I0 \times \bar{S})}$$

$$2\bar{Y} = \overline{\overline{OE} \times (2I1 \times S + 2I0 \times \bar{S})}$$

$$3\bar{Y} = \overline{\overline{OE} \times (3I1 \times S + 3I0 \times \bar{S})}$$

$$4\bar{Y} = \overline{\overline{OE} \times (4I1 \times S + 4I0 \times \bar{S})}$$

The 74HC258 is identical to the 74HC257 but has inverting outputs.

2. Features

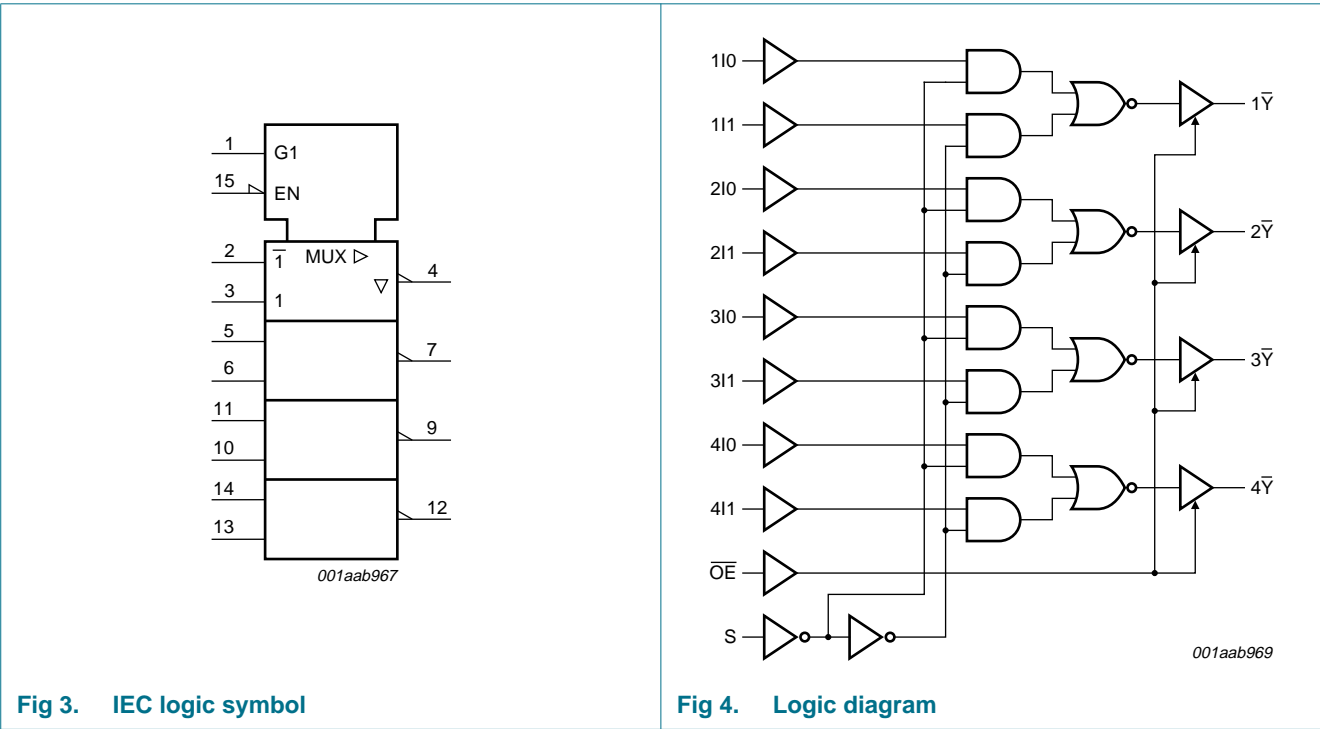
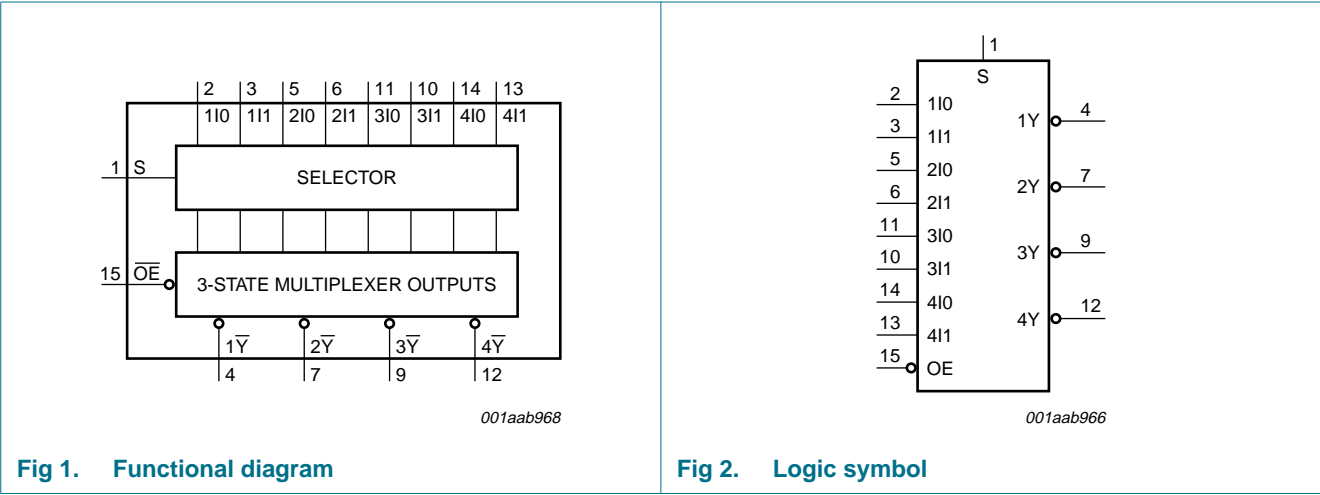
- 3-state outputs interface directly with system bus
- Low-power dissipation
- Inverting data path
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C.

3. Ordering information

Table 1. Ordering information

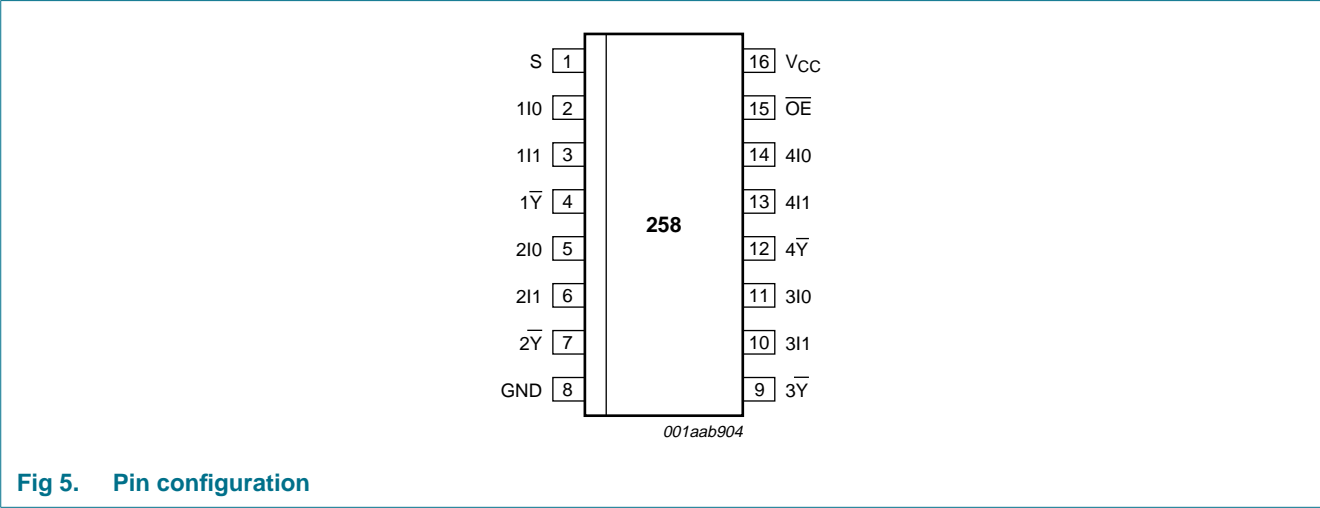
Type number	Package			
	Temperature range	Name	Description	Version
74HC258N	−40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HC258D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC258DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1

4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
S	1	common data select input
1I0	2	data input 1 from source 0
1I1	3	data input 1 from source 1
1Y	4	3-state multiplexer output 1; inverted
2I0	5	data input 2 from source 0
2I1	6	data input 2 from source 1
2Y	7	3-state multiplexer output 2; inverted
GND	8	ground (0 V)
3Y	9	3-state multiplexer output 3; inverted
3I1	10	data input 3 from source 1
3I0	11	data input 3 from source 0
4Y	12	3-state multiplexer output 4; inverted
4I1	13	data input 4 from source 1
4I0	14	data input 4 from source 0
OE	15	output enable input (active LOW)
VCC	16	positive supply voltage

6. Functional description

Table 3. Function table^[1]

Control		Input		Output
$\overline{\text{OE}}$	S	nI0	nI1	n $\overline{\text{Y}}$
H	X	X	X	Z
L	L	L	X	H
L	L	H	X	L
L	H	X	L	H
L	H	X	H	L

- [1] H = HIGH voltage level;
 L = LOW voltage level;
 X = don't care;
 Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I_{IK}	input clamping current	$V_{\text{I}} < -0.5 \text{ V}$ or $V_{\text{I}} > V_{\text{CC}} + 0.5 \text{ V}$	^[1] -	± 20	mA
I_{OK}	output clamping current	$V_{\text{O}} < -0.5 \text{ V}$ or $V_{\text{O}} > V_{\text{CC}} + 0.5 \text{ V}$	^[1] -	± 20	mA
I_{O}	output current	$V_{\text{O}} = -0.5 \text{ V}$ to $V_{\text{CC}} + 0.5 \text{ V}$	-	± 35	mA
I_{CC}	supply current		-	70	mA
I_{GND}	ground current		-70	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{\text{amb}} = -40 \text{ °C}$ to $+125 \text{ °C}$			
		DIP16 package	^[2] -	750	mW
		SO16 package	^[3] -	500	mW
		SSOP16 package	^[4] -	500	mW

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 [2] P_{tot} derates linearly with 12 mW/K above 70 °C.
 [3] P_{tot} derates linearly with 8 mW/K above 70 °C.
 [4] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
T_{amb}	ambient temperature		-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0\text{ V}$	-	-	625	ns
		$V_{CC} = 4.5\text{ V}$	-	1.67	139	ns
		$V_{CC} = 6.0\text{ V}$	-	-	83	ns

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0\text{ V}$	1.5	1.2	-	1.5	-	1.5	-	V
		$V_{CC} = 4.5\text{ V}$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0\text{ V}$	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0\text{ V}$	-	0.8	0.5	-	0.5	-	0.5	V
		$V_{CC} = 4.5\text{ V}$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0\text{ V}$	-	2.8	1.8	-	1.8	-	1.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 6.0\text{ V}$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_O = -6\text{ mA}; V_{CC} = 4.5\text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level output voltage	$I_O = -7.8\text{ mA}; V_{CC} = 6.0\text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
		$V_I = V_{IH}$ or V_{IL}								
		$I_O = 20\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20\text{ }\mu\text{A}; V_{CC} = 6.0\text{ V}$	-	0	0.1	-	0.1	-	0.1	V
I_I	input leakage current	$I_O = 6\text{ mA}; V_{CC} = 4.5\text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 7.8\text{ mA}; V_{CC} = 6.0\text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
		$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\text{ V}$	-	-	± 0.1	-	± 1.0	-	± 1.0	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}; V_{CC} = 6.0\text{ V};$ $V_O = V_{CC}$ or GND; $I_O = 0\text{ A}$	-	-	± 0.5	-	± 5.0	-	± 10	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0\text{ A};$ $V_{CC} = 6.0\text{ V}$	-	-	8	-	80	-	160	μA
C_I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +125 °C		Unit
			Min	Typ	Max	Max (85 °C)	Max (125 °C)	
t_{pd}	propagation delay	nI0, nI1 to n \bar{Y} ; see Figure 6 [1]						
		$V_{CC} = 2.0\text{ V}$	-	30	95	120	145	ns
		$V_{CC} = 4.5\text{ V}$	-	11	19	24	29	ns
		$V_{CC} = 6.0\text{ V}$	-	9	16	20	25	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	9	-	-	-	ns
		S to n \bar{Y} ; see Figure 6						
		$V_{CC} = 2.0\text{ V}$	-	47	140	175	210	ns
		$V_{CC} = 4.5\text{ V}$	-	17	28	35	42	ns
		$V_{CC} = 6.0\text{ V}$	-	14	24	30	36	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	14	-	-	-	ns
t_{en}	enable time	\overline{OE} to n \bar{Y} ; see Figure 7 [2]						
		$V_{CC} = 2.0\text{ V}$	-	39	140	175	210	ns
		$V_{CC} = 4.5\text{ V}$	-	14	28	35	42	ns
		$V_{CC} = 6.0\text{ V}$	-	11	24	30	36	ns
t_{dis}	disable time	\overline{OE} to n \bar{Y} ; see Figure 7 [3]						
		$V_{CC} = 2.0\text{ V}$	-	55	150	190	225	ns
		$V_{CC} = 4.5\text{ V}$	-	20	30	38	45	ns
		$V_{CC} = 6.0\text{ V}$	-	16	26	33	38	ns
t_t	transition time	see Figure 6 [4]						
		$V_{CC} = 2.0\text{ V}$	-	14	60	75	90	ns
		$V_{CC} = 4.5\text{ V}$	-	5	12	15	18	ns
		$V_{CC} = 6.0\text{ V}$	-	4	10	13	15	ns
C_{PD}	power dissipation capacitance	per multiplexer; $V_I = \text{GND to } V_{CC}$ [5]	-	55	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[4] t_t is the same as t_{THL} and t_{TLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

11. Waveforms

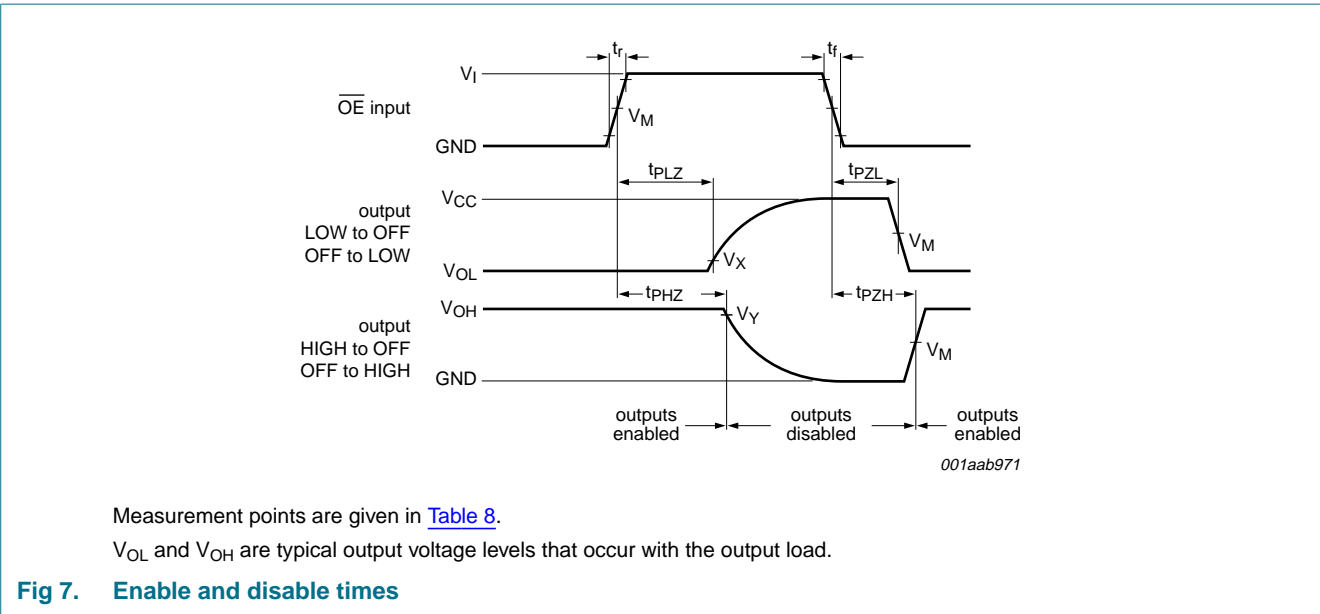
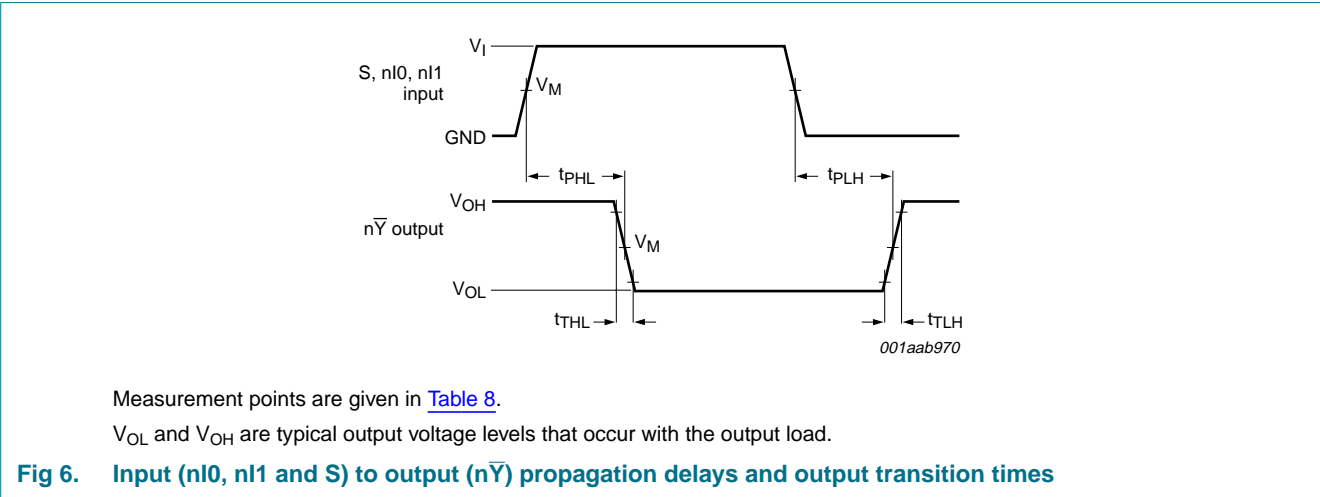


Table 8. Measurement points

Input	Output		
V_M	V_M	V_X	V_Y
$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

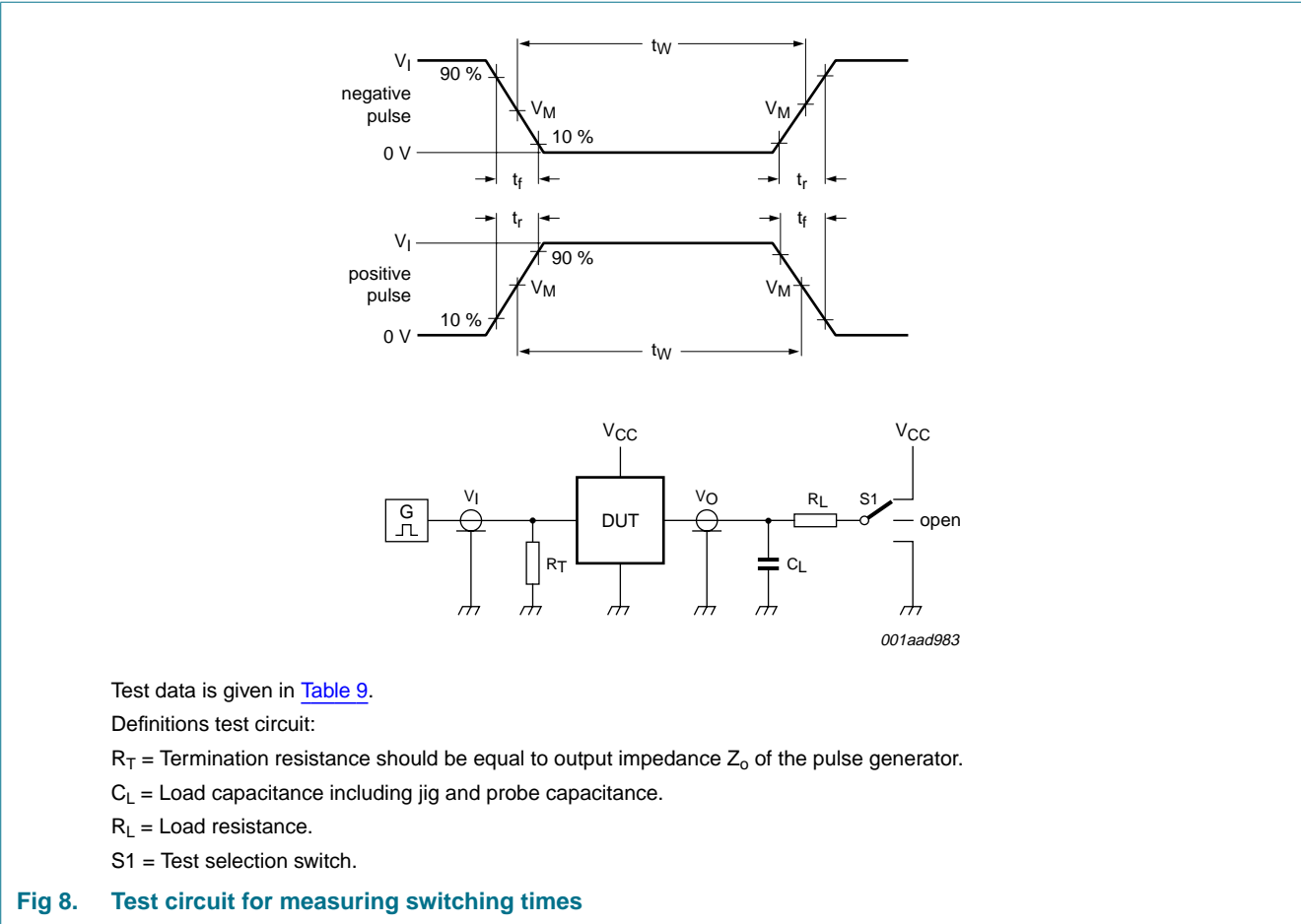


Table 9. Test data

Supply voltage	Input		Load		S1		
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PZL}, t_{PLZ}	t_{PZH}, t_{PHZ}	t_{PHL}, t_{PLH}
2.0 V	V_{CC}	6 ns	50 pF	1 k Ω	V_{CC}	GND	open
4.5 V	V_{CC}	6 ns	50 pF	1 k Ω	V_{CC}	GND	open
6.0 V	V_{CC}	6 ns	50 pF	1 k Ω	V_{CC}	GND	open
5.0 V	V_{CC}	6 ns	15 pF	1 k Ω	V_{CC}	GND	open

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

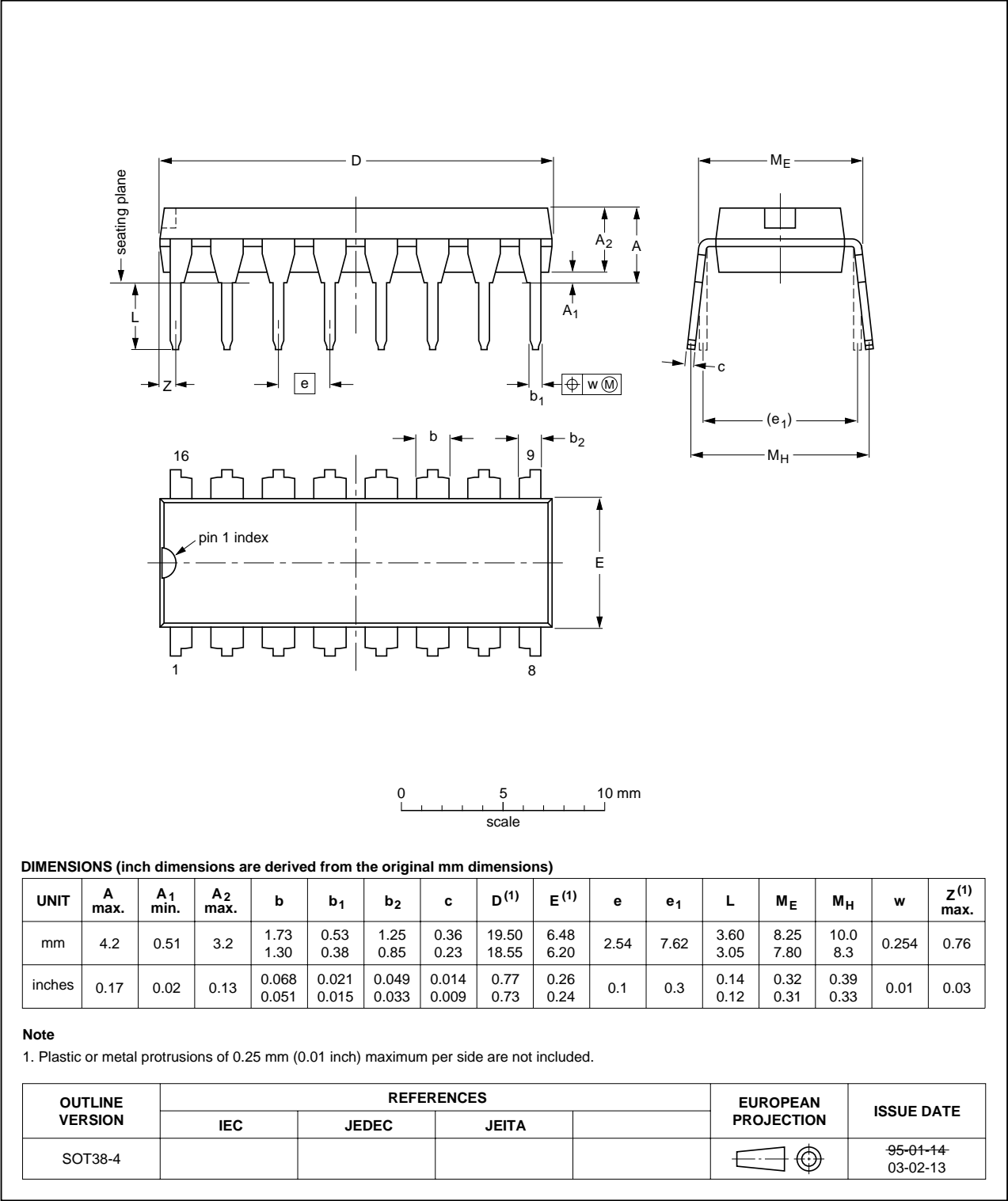
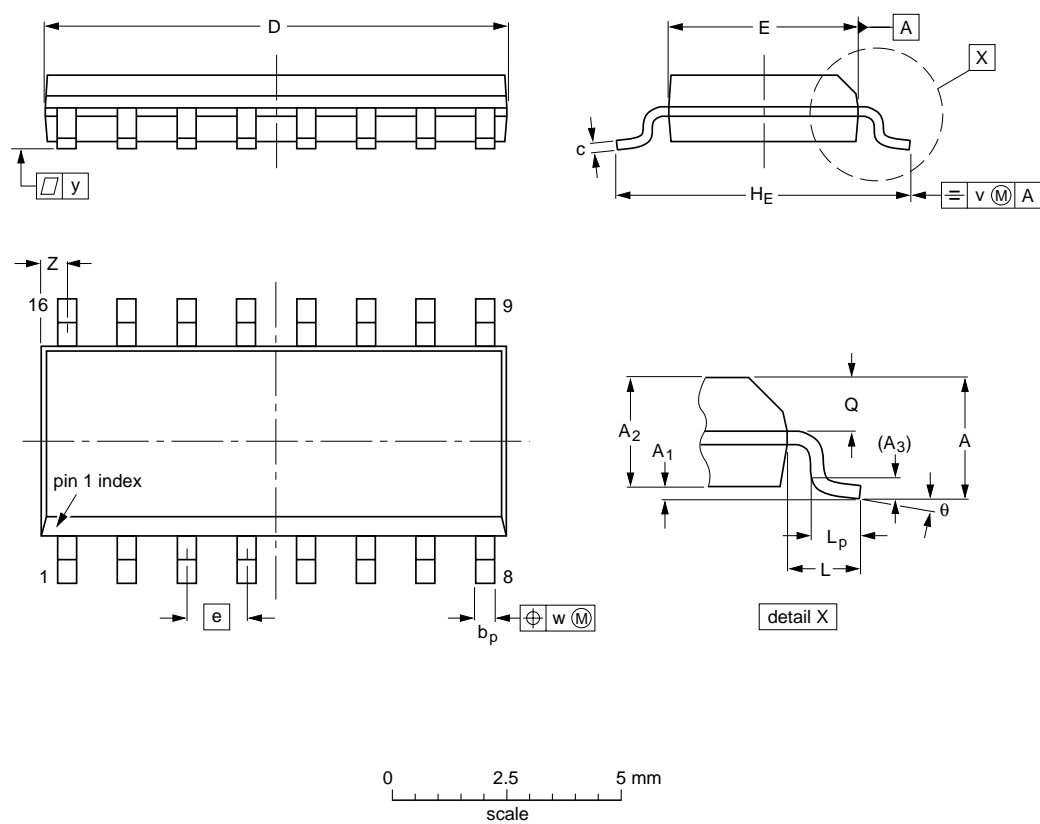


Fig 9. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig 10. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

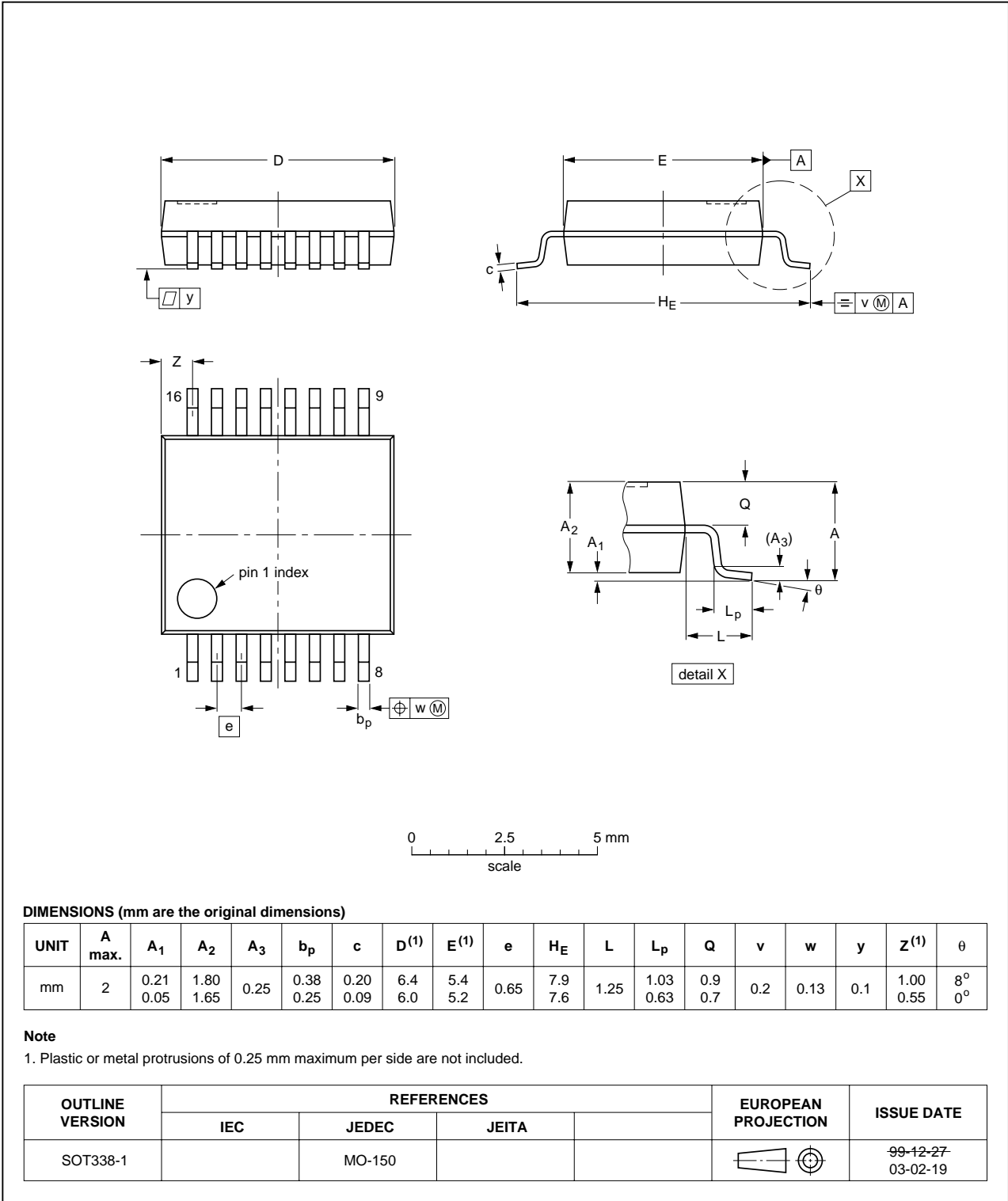


Fig 11. Package outline SOT338-1 (SSOP16)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC258_4	20080414	Product data sheet	-	74HC258_3
Modifications:	<ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.• Pin assignment corrected for pins 10, 11, 13 and 14 in Figure 1, Figure 2, Figure 5 and Table 2.			
74HC258_3	20041112	Product data sheet	-	74HC_HCT258_CNV_2
74HC_HCT258_CNV_2	19990902	Product specification	-	74HC_HCT258_1
74HC_HCT258_1	19901201	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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